

SR520-G Thru. SR5200-G

Forward current: 5.0A

Reverse voltage: 20 to 200V

RoHS Device

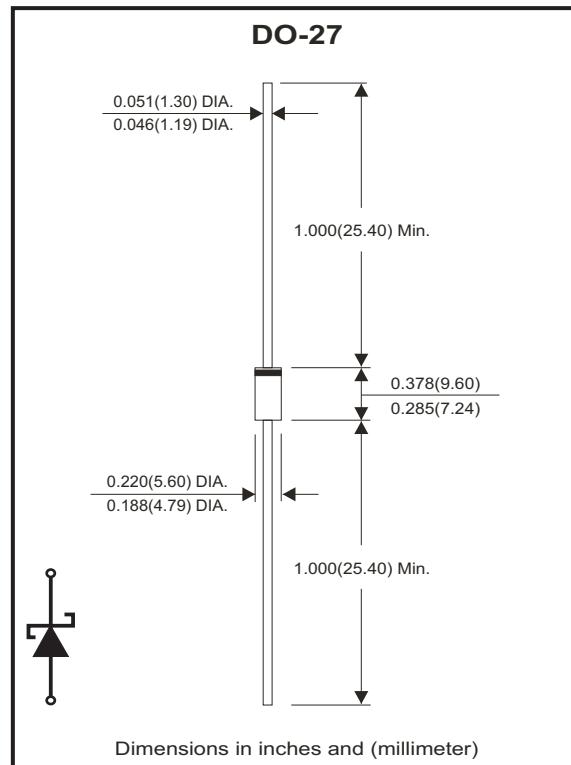


Features

- Axial lead type devices for through hole design.
- Low power loss, high efficiency.
- High current capability, Low forward voltage drop.
- High surge capability.
- Guard ring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free part meets environmental standards of MIL-STD-19500/228

Mechanical Data

- Case: Molded plastic, DO-201AD/DO-27
- Epoxy: UL94V-0 rate flame retardant.
- Lead: Axial lead, solderable per MIL-STD-202, Method 208 guaranteed.
- Polarity: color band denoted cathode end.
- Weight: 1.10 grams(approx.).



Maximum Ratings and Electrical Characteristics

Ratings at Ta=25°C unless otherwise noted.

Single phase, half wave, 60Hz, resistive or inductive loaded.

For capacitive load, derate current by 20% .

Parameter	Symbol	SR520 -G	SR540 -G	SR560 -G	SR5100 -G	SR5150 -G	SR5200 -G	Unit
Maximum recurrent peak reverse voltage	V _{RRM}	20	40	60	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	28	42	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	40	60	100	150	200	V
Maximum instantaneous forward voltage at If=5A, Ta=25°C	V _F	0.50	0.55	0.75	0.81	0.87	0.90	V
Typical diode Junction capacitance f=1MHZ and applied 4V DC reverse Voltage	C _J	380			300			pF
Operating junction temperature range	T _J			-50 ~ +150			-50 ~ +175	°C

f=1MHz and applied 4V DC reverse Voltage

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	Unit
Forward rectified current	See Fig.1	I _o			5.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}			125	A
Reverse Current	V _R = V _{RRM} TA=25°C	I _R			0.5	mA
	V _R = V _{RRM} TA=100°C	I _R			20	mA
Thermal Resistance	Junction to ambient	R _{θJA}		24		°C/W
Storage temperature		T _{STG}	-50		+175	°C

Company reserves the right to improve product design , functions and reliability without notice.

REV:B

Schottky Barrier Rectifier

Comchip
SMD Diode Specialist

RATING AND CHARACTERISTIC CURVES (SR520-G Thru. SR5200-G)

Fig.1 - Typical Forward Current Derating Curve

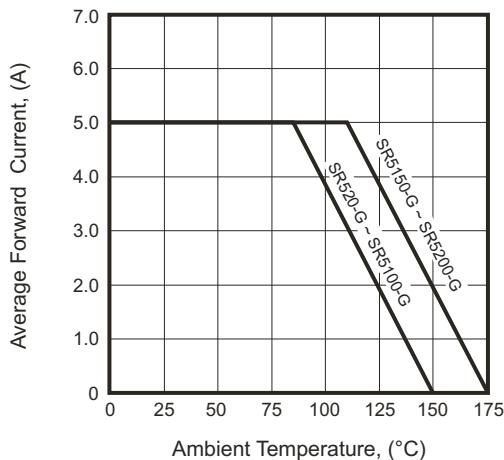


Fig.2 - Typical Forward Characteristics

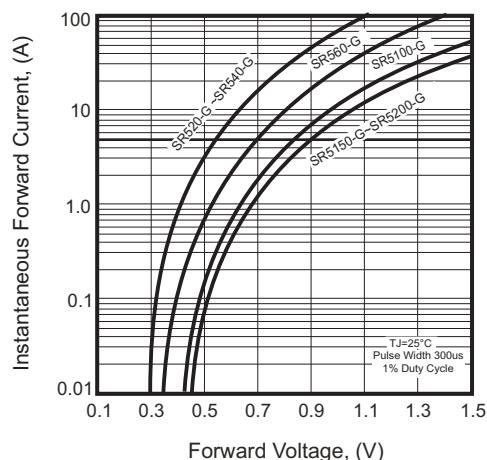


Fig.3 - Maximum Non-repetitive Forward Surge Current

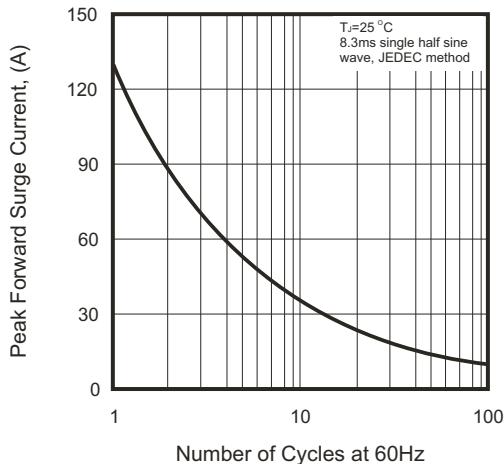


Fig.4 - Typical Junction Capacitance

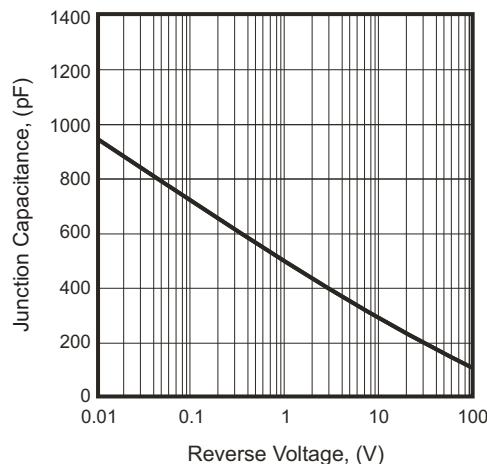
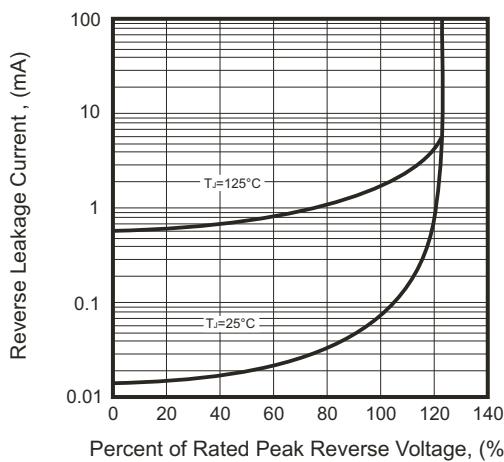


Fig.5 - Typical Reverse Characteristics



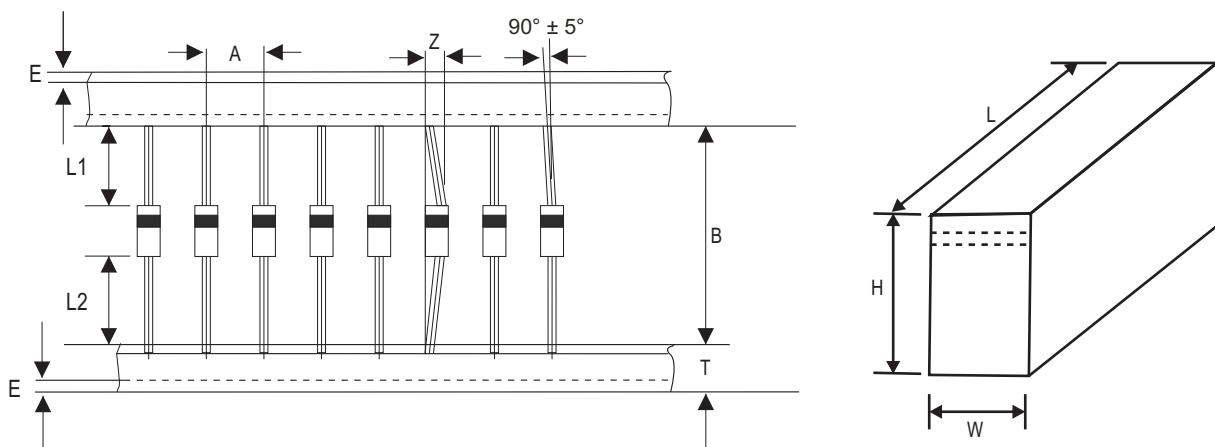
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REV:B

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Taping Specification For Axial Lead Diodes

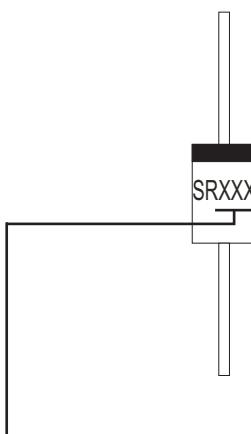


DO-27	SYMBOL	A	B	Z	T	E
	(mm)	10.00 ± 0.50	52.40 (max)	1.60 (max)	6.00 ± 0.40	3.00 (max)
	(inch)	0.394 ± 0.020	2.063 (max)	0.062 (max)	0.236 ± 0.016	0.118 (max)

DO-27	SYMBOL	$ L_1-L_2 $	L	W	H
	(mm)	1.00(max)	260 ± 5.00	75 ± 5.00	145 ± 5.00
	(inch)	0.039(max)	10.236 ± 0.197	2.953 ± 0.197	5.709 ± 0.197

Marking Code

Part Number	Marking Code
SR520-G	SR52
SR540-G	SR54
SR560-G	SR56
SR5100-G	SR510
SR5150-G	SR515
SR5200-G	SR520



XX / XXX = Product type marking code

Standard Packaging

Case Type	AMMO PACK	
	BOX (pcs)	CARTON (pcs)
DO-27	500	9,000